

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
001/	18mΩ @ V <sub>GS</sub> = 10V	9.4A
60V	27.5mΩ @ V <sub>GS</sub> = 4.5V	7.6A

### **Features**

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production: Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub>—Ensures On-State Losses Are Minimized
- 0.6mm Profile—Ideal for Low-Profile Applications
- PCB Footprint of 4mm<sup>2</sup>
- Sidewall Plated for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The DMTH6016LFDFWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

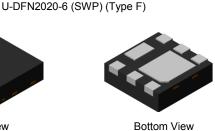
## **Mechanical Data**

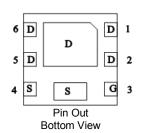
- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-Matte Tin Annealed over CopperLead-Frame; Solderable per MIL-STD-202, Method 208 (e3
- Weight: 0.007 grams (Approximate)

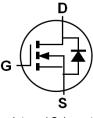


This MOSFET is designed to meet the stringent requirements of automotive applications. The device is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- **Power Management Functions**
- **DC-DC Converters**
- Backlighting







Internal Schematic

## Ordering Information (Note 4 & 5)

Top View

Part Number	Case	Quantity Per Reel
DMTH6016LFDFWQ-7	U-DFN2020-6 (SWP) (Type F)	3,000
DMTH6016LFDFWQ-7R	U-DFN2020-6 (SWP) (Type F)	3,000
DMTH6016LFDFWQ-13	U-DFN2020-6 (SWP) (Type F)	10,000
DMTH6016LFDFWQ-13R	U-DFN2020-6 (SWP) (Type F)	10,000

Notes: 1. No purposely added lead, Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. The options -7 and -7R stand for different taping orientations. Please refer to Diodes Incorporated's website at https://www.diodes.com for further details. 5. For packaging details, see https://www.diodes.com/design/support/packaging/diodes-packaging/.

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## **Marking Information**



66 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020)

M = Month (ex: 9 = September)

Date	Code	Key

Year	2	017	2018	20	)19	2020	20	21	2022	202	3	2024
Code		E	F	(	G	Н	I		J	K		L
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

## Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	60	V	
Gate-Source Voltage	V <sub>GSS</sub>	V <sub>GSS</sub> ±20		
Continuous Drain Current (Note 7) $V_{GS}$ = 10V	ID	9.4 6.6	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	70	А	
Continuous Source-Drain Diode Current (Note 7)	Is	3.0	А	
Pulsed Source-Drain Diode Current (10µs Pulse, Duty Cycle	I <sub>SM</sub>	70	А	
Avalanche Current, L = 0.1mH	I <sub>AS</sub>	15.3	А	
Avalanche Energy, L = 0.1mH	E <sub>AS</sub>	11.7	mJ	

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	1.06	W
Thermal Resistance, Junction to Ambient (Note 6)		R <sub>0JA</sub>	141	°C/W
Total Power Dissipation (Note 7)	T <sub>A</sub> = +25°C	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 7)		R <sub>0JA</sub>	63	°C/W
Thermal Resistance, Junction to Case (Note 7)	T <sub>C</sub> = +25°C	R <sub>θJC</sub>	9.6	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:



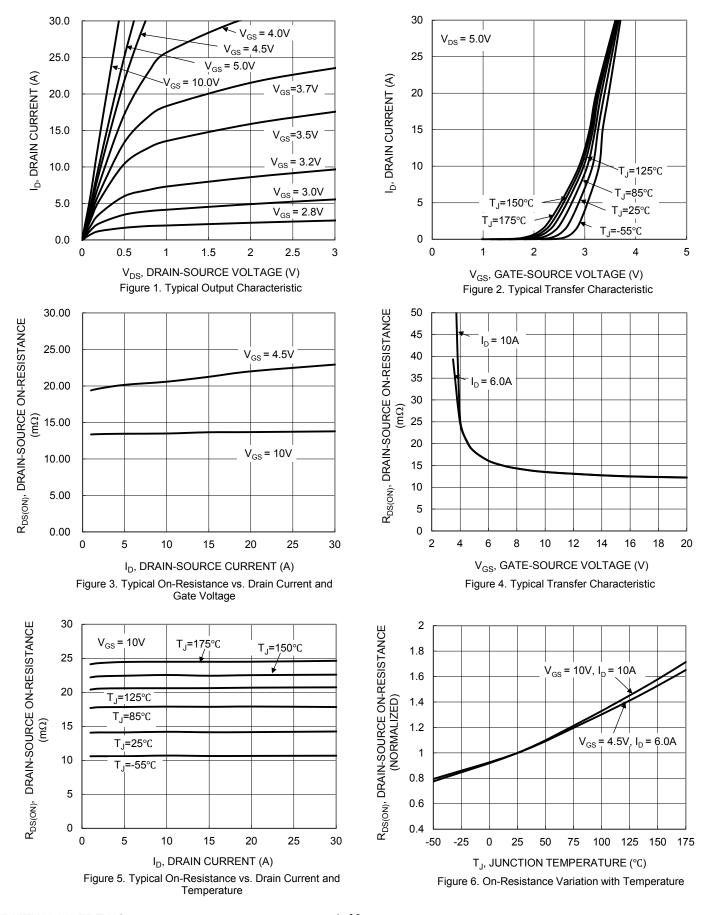
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	·		•			·	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	—	V	$V_{GS}$ = 0V, I <sub>D</sub> = 250µA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	1	μA	V <sub>DS</sub> = 48V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	—	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	—	3	V	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A	
Static Drain-Source On-Resistance	<b>D</b>		13.8	18	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 10A	
	R <sub>DS(ON)</sub>	_	20.3	27.5	11152	$V_{GS}$ = 4.5V, $I_{D}$ = 6A	
Diode Forward Voltage	V <sub>SD</sub>	—	—	1.0	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 10A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	—	925	—			
Output Capacitance	C <sub>oss</sub>	—	242	—	pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	—	25.4	—			
Gate Resistance	Rg	—	1.3	—	Ω	$V_{DS}$ = 0V, $V_{GS}$ = 0V, f = 1MHz	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	—	7.5	—			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	15.3	—	nC		
Gate-Source Charge	Qgs	—	2.6	—	nc	V <sub>DS</sub> = 30V, I <sub>D</sub> = 10A	
Gate-Drain Charge	Q <sub>gd</sub>	—	3.5	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	—	3.2	_			
Turn-On Rise Time	t <sub>R</sub>	_	4.2	—	20	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 30V,	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	14.5	—	ns	$R_g = 6\Omega$ , $I_D = 10A$	
Turn-Off Fall Time	tF	—	7.2	_			
Reverse Recovery Time	t <sub>RR</sub>	_	20.8	—	ns		
Reverse Recovery Charge	Q <sub>RR</sub>	_	11.4		nC	I <sub>F</sub> = 10A, di/dt = 100A/μs	

Notes:8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to product testing.



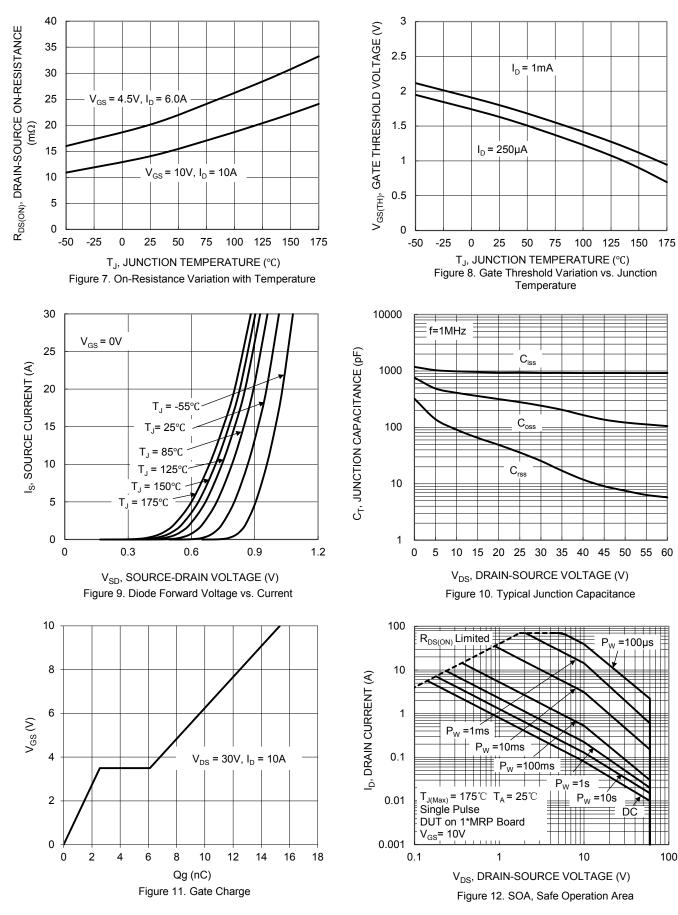
# DMTH6016LFDFWQ



DMTH6016LFDFWQ Datasheet number: DS40959 Rev. 4 - 2



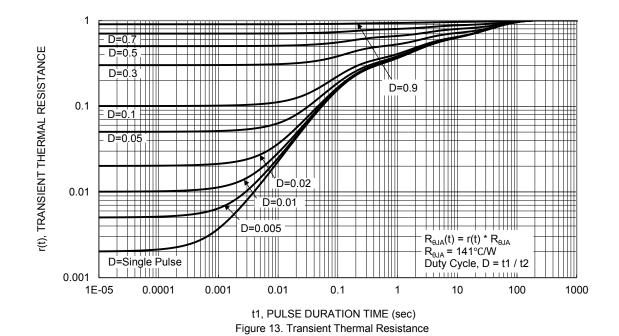
# DMTH6016LFDFWQ



DMTH6016LFDFWQ Datasheet number: DS40959 Rev. 4 - 2

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DMTH6016LFDFWQ Datasheet number: DS40959 Rev. 4 - 2



Тур

0.62

0.03 0.192

0.33

2.00

0.97

0.40

2.00

1.17

0.72

0.15

0.375

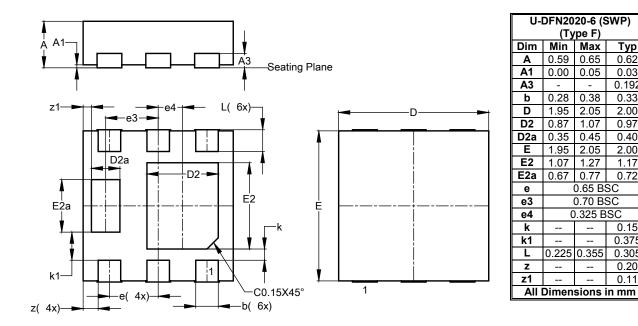
0.305

0.20

0.11

## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

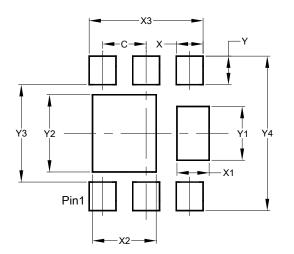


#### U-DFN2020-6 (SWP) (Type F)

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-6 (SWP) (Type F)



1			
Dimensions	Value		
Dimensions	(in mm)		
С	0.650		
Х	0.400		
X1	0.480		
X2	0.950		
X3	1.700		
Y	0.425		
Y1	0.800		
Y2	1.150		
Y3	1.450		
Y4	2.300		



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